

5A/10A, 60Vdc Optically Isolated, Short-Circuit Protected

DC Solid-State Relay

Part Number*	Description
KD00CK	5A Solid State Relay
KD02CK	5A SSR with Switch Status
KD20CK	5A SSR with Short Circuit Protection
KD22CK	5A SSR with Short Circuit Protection and Switch Status
LD00CM	10A Solid State Relay
LD02CM	10A SSR with Switch Status
LD20CM	10A SSR with Short Circuit Protection
LD22CM	10A SSR with Short Circuit Protection and Switch Status

*The Y suffix denotes parameters tested to MIL-PRF-28750 Specifications. The W suffix denotes parameters tested to Teledyne Specifications.

ELECTRICAL SPECIFICATIONS

(-55°C to +105°C UNLESS OTHERWISE NOTED)

INPUT (CONTROL) SPECIFICATIONS

When used in 2 terminal configuration

(TTL or direct control) (See Fig. 1)	Min	Тур	Max	Units
Input Current @ $V_{BIAS} = 5 V_{DC}$ (See Fig 2)			15	mA
Turn-Off Voltage (Guaranteed Off)			1.5	V_{DC}
Turn-On Voltage (Guaranteed On)	3.8			V_{DC}
Reverse Voltage Protection			-32	V_{DC}
Input Supply Range (See Note 1, 7)	3.8		16	V_{DC}

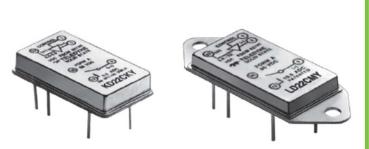
INPUT (CONTROL) SPECIFICATIONS

When used in 3 terminal configuration

(CMOS or open collector TTL)	Min	Тур	Max	Units
Control Current $V_{CONTROL} = 5 V_{DC}$			250	μA _{DC}
V _{CONTROL} = 18 V _{DC (See Note 7)}			1.0	mA_{DC}
Control Voltage Range (See Note 7)	0		18	V_{DC}
Bias Supply Voltage (See Note 1, 7)	3.8		32	V_{DC}
Bias Supply Current @ $V_{BIAS} = 5 V_{DC}$			16	mA
Control Turn-Off Voltage (Guaranteed Off)	3.2			V_{DC}
Control Turn-On Voltage (Guaranteed On)			0.3	V_{DC}

ENVIRONMENTAL SPECIFICATIONS

Temperature Range	Min	Max	Units
Operating	-55	+125	°C
Storage	-55	+125	°C
Vibration, 100 g	10	3000	Hz
Constant Acceleration		5000	g
Shock, 0.5 ms pulse		1500	g



FEATURES

- · Available with short-circuit/current overload protection
- · Available with switch status output
- TTL and CMOS compatible control
- · Low ON resistance power FET output
- · Fast switching speed
- Meets 28 Vdc system requirements of MIL-STD-704
- · Optical isolation
- · Low profile hermetic package
- Built and tested to the requirements of MIL-PRF-28750

DESCRIPTION

The Series KD and LD solid-state relays are screened utilizing MIL-PRF-28750 test methods and are packaged in low profile hermetically sealed cases. These relays are constructed with state-of-the-art solid state techniques and feature fully floating power FET output technology. This allows the load to be connected to either output terminal and provides a low ON resistance. The input (control) and output are optically isolated to protect input logic circuits from output transients. Available options include short circuit and current overload protection, which provides complete protection for both the relay and system wiring. This feature not only provides protection should a short or overload occur while the relay is on, but will also provide protection should the relay be switched into a short. The second option is a status output line. Switch status returns the true status of the output switch and is optically isolated from the load. It provides status indication independent of the control circuit of the relay. The status line provides a logic 0 (low) when the relay output is off with load voltage and continuity present, and a logic 1 (high) when the output is on.



5A/10A, 60Vdc Optically Isolated, DC Solid-State Relay

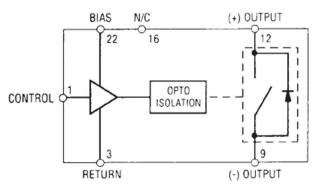
ELECTRICAL SPECIFICATIONS, CONT.

(-55°C to +105°C UNLESS OTHERWISE NOTED)

LD series with heatsink10 A_{DC} Leakage Current @ V _{LOAD} = 60 V _{DC} KD00CK, KD20CK100 μA LD00CM, LD20CM100 μA LD02CM, LD20CM2mAOutput Voltage Drop KD00CK, KD20CK0.6V _{DC} LD02CM, LD20CM0.7V _{DC} LD02CM, LD20CM0.7V _{DC} Continuous Operating Load Voltage560V _{DC} Transient Blocking Voltage @ 25°C80V _{Pk} ON Resistance R _{d6} (on) (See Fig 4) KD00CK, KD20CK.075 Ω LD00CM, LD20CM.075 Ω KD00CK, KD22CK.100 Ω Turn-On Time (See Fig. 5)5mSTurn-Off Time (See Fig. 5)2mSElectrical System Spike (See Note 7)±600V _{DC} Output Capacitance at 25 Vdc, 100 KHz (See Note 7)100pFIsolation (Input to Output) (See Note 7)100pFKD00CK, KD20CK LD00CM, LD20CM10pFDielectric Strength @ 25°C10% Ω Output Junction Temperature @ I _{LOAD} = I _{max rated} 130°CMaximum Junction Temperature130°CMaximum Junction Temperature150°CThermal Resistance Junction to Ambient (θ_{JA})30°C/M	OUTPUT (LOAD) SPECI	FICATIO Min Typ		Units
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KD00CK, KD20CK100 μA LD00CM, LD20CM100 μA KD02CK, KD22CK2mAOutput Voltage Drop0.6VDCKD00CK, KD20CK0.6VDCLD02CM, LD2CM0.7VDCLD02CM, LD2CM @ 10A1.4VDCContinuous Operating Load Voltage560VDCTransient Blocking Voltage @ 25°C80VpkON Resistance Rds (on) (See Fig 4).075 Ω KD00CK, KD20CK.075 Ω Ω LD02CM, LD22CM.0075 Ω LD00CM, LD20CM.075 Ω KD02CK, KD22CK.100 Ω LD02CM, LD22CM.00 Ω LD02CM, LD22CM.00 Ω Cortinuous Cperating (See Fig 4).075 Ω KD00CK, KD20CK.075 Ω LD02CM, LD22CM.00 Ω Turn-On Time (See Fig. 5)5mSTurn-Off Time (See Fig. 5)2mSElectrical System Spike (See Note 7) ± 600 V_{DC} Output Capacitance at 25 Vdc, 100 KHz10 pF Isolation (Input to Output) (See Note 7) FF FF LD00CM, LD20CM10 pF KD00CK, KD20CK10 pF LD02CM, LD22CM15 pF Dielectric Strength @ 25°C1000 V_{AC} Insulation Resistance @ 500V_DC @ 25°C 10° Ω Maximum Junction Temperature130°CMaximum Junction Temperature150°CThermal Resistance J	LD series with heatsink		10	A_{DC}
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KD02CK, KD22CK LD02CM, LD22CM15 pF pFDielectric Strength @ 25°C1000 V_{AC} Insulation Resistance @ 500V _{DC} @ 25°C10° Ω Output Junction Temperature @ I _{LOAD} = I _{max rated} 130°CMaximum Junction Temperature150°CThermal Resistance Junction to Ambient (θ_{JA})30°C/W				
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Output Junction Temperature (@ $I_{LOAD} = I_{max rated}$ 130°CMaximum Junction Temperature150°CThermal Resistance Junction to Ambient (θ_{JA})30°C/W	Dielectric Strength @ 25°C	1000		V_{AC}
(@ $I_{LOAD} = I_{max rated}$ 130CMaximum Junction Temperature150°CThermal Resistance Junction to Ambient (θ_{JA})30°C/W	Insulation Resistance @ 500V _{DC} @ 25°	°C 10 ⁹		Ω
Thermal Resistance Junction to Ambient (θ_{JA}) 30 °C/W			130	°C
	Maximum Junction Temperature		150	°C
Thermal Resistance Junction to Case (θ_{JC}) 7 °C/W	Thermal Resistance Junction to Ambier	nt (θ _{JA})	30	°C/W
	Thermal Resistance Junction to Case (θ _{JC})	7	°C/W

BLOCK DIAGRAMS BIAS STATUS (+) OUTPUT 12 22 16 f OPTO ISOLATION OPTO CONTROL ISOLATION 3 q (-) OUTPUT RETURN

WITH STATUS



NO STATUS

STATUS OUTPUT TRUTH TABLE

	(KD02CK, LD02CM, KD22CK, LD22CM)				
State Status					
	Control Voltage	Output Level			
	High	Off	Low (V _{SO} \leq 0.4 V)		
Low		On	High (V _{SO} = V _{STATUS})		

STATUS OUTPUT SPECIFICATIONS

(KD02CK, LD02CM, KD22CK, LD22CM)

	·	Max	Units
Status Supply Voltage		30	V_{DC}
Status Leakage Current @ 16V _{DC} @ 30V _{DC}		10 100	μΑ _{DC} μΑ _{DC}
Status (sink) Current (V _{SO} < 0.4 Vdc)		600	μA_{DC}
Status Turn-On Time (See Fig. 6)		3.5	ms
Status Turn-Off Time (See Fig. 6)		8.0	ms

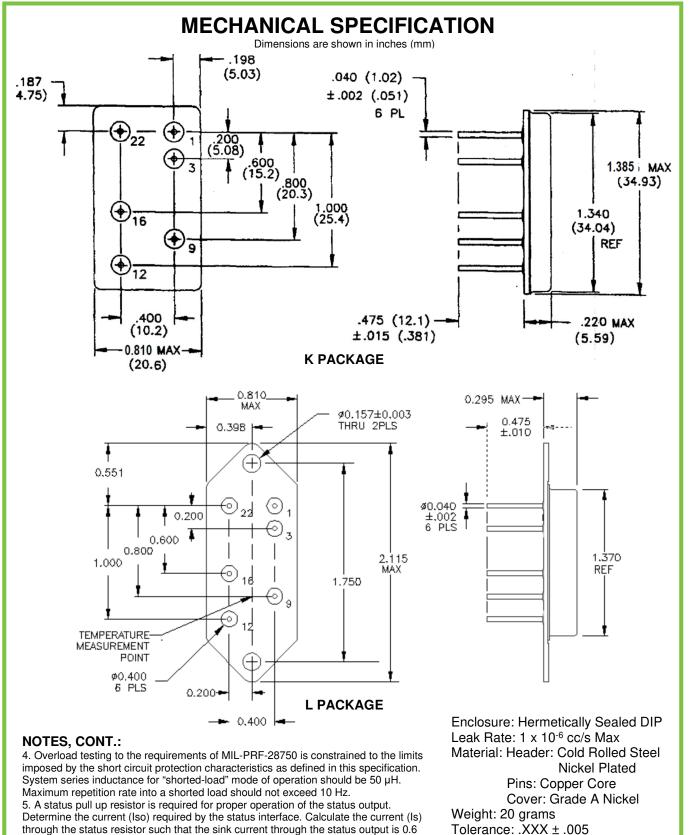
NOTES:

1. Control input is compatible with CMOS or open collector TTL (with pull up resistor). For bias voltages above 6V, a series resistor is required. Use the standard resistor value equal to or less than the value found in Figure 8.

2. The rated input voltage is 5V for all tests unless otherwise specified. – 3. To calculate the maximum ON resistance for a given junction temperature, find the normalized ON resistance factor (NR) from Figure 4. Calculate the new ON resistance as follows: $R_{(ON)} = NR \cdot R_{ON} @ 25^{\circ}C$ (for KD00CK, LD00CM, KD02CK, LD02CM) $R_{(ON)} = NR(R_{ON} @ +25^{\circ}C) + .025$ ohm (for KD20CK, LD20CM, KD22CK, LD22CM)



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through the status output. $R_{STATUS} = (V_{STATUS} - 0.4V) / Iso$ 6. Inductive loads should be diode suppressed. Input transitions should be ≤ 1 ms duration and the input drive should be a bounceless contact type.

mA. Select the status resistor such that it does not allow more than 0.6 mA to flow

7. Parameter Guaranteed by design, but not tested 100% in product acceptance.



30

KD20CK

KD22CK LD20CM

LD22CN

40

50

60

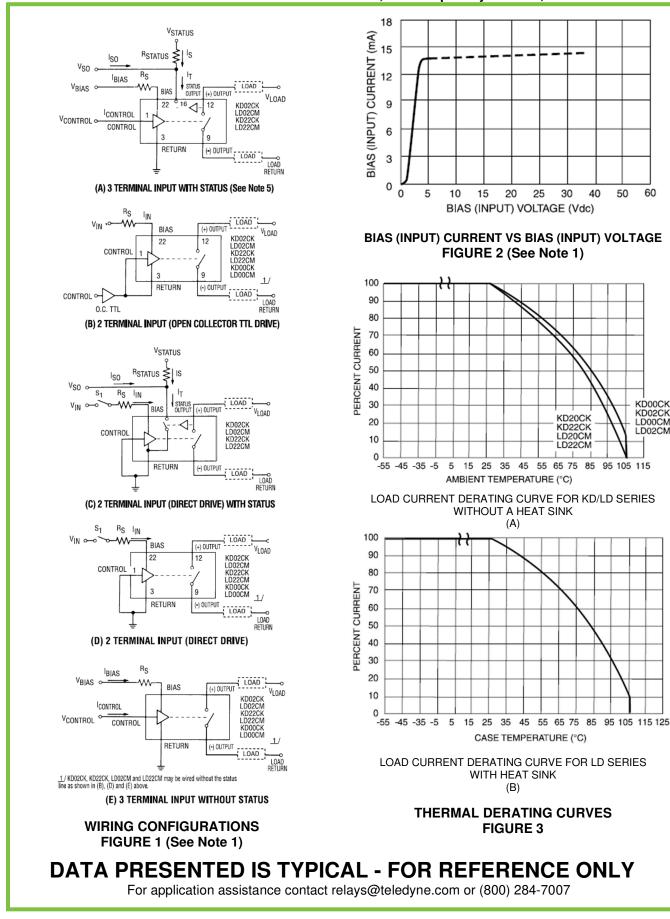
KD00CK

KD02CK LD00CM

LD02CM



5A/10A, 60Vdc Optically Isolated, DC Solid-State Relay





5A/10A, 60Vdc Optically Isolated, DC Solid-State Relay

